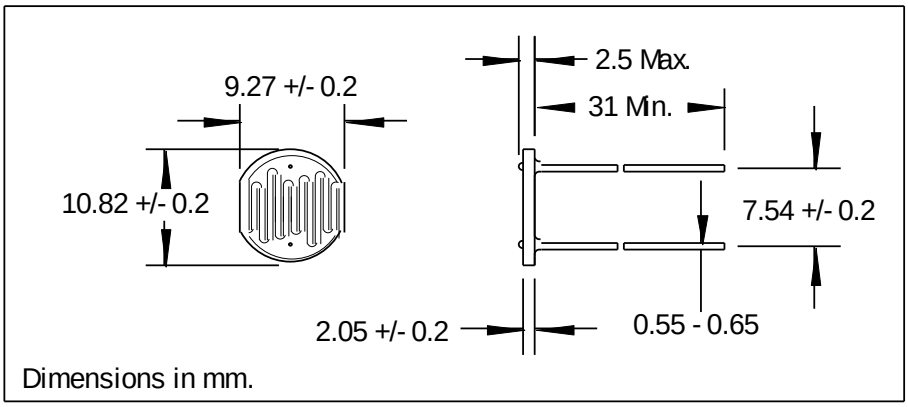
TO-8 Ceramic Photocell

NSL-4952



FEATURES

- Passive resistance output
- Plastic coated

DESCRIPTION

The NSL-4952 is a CdS photoconductive cell in a TO-8 ceramic package.

APPLICATIONS

- Industrial

ABSOLUTE MAXIMUM RATING

(TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	PARAMETER	MIN	MAX	UNITS
V_P	Voltage (peak AC or DC)		320	V
P_d	Power Dissipation @ 25˚C (1)		250	mW
T_{Op}	Operating Temperature	-60	+75	°C
T_{Stg}	Storage Temperature	-60	+75	°C
T_S	Soldering Temperature (2)		+260	°C

Note:

(1) Derate linearly to 0 at 75°C

(2) >0.08" from case for <5 sec.

(3) Cells light adapted at 30 to 50 Ftc for 16 hrs minimum prior to electrical tests.

(4) Print "**NSL-4952**" and date code "**YYWW**".

RELIABILITY

Contact API for recommendations on specific test conditions and procedures.

ELECTRO-OPTICAL CHARACTERISTICS

(TA)= 23°C, UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
R_L	Light Resistance	1 ftc., 2854˚K (3)	24	40	56	KΩ
		100 ftc., 2854˚K (3)		860		Ω
R_D	Dark Resistance	5 sec after removal of test light.	2.4			MΩ
λ_P	Spectral Peak			515		nm

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